## NSN 5962-01-371-3175

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-371-3175

| Features Provided:   |
|--|
| Programmed and electrostatic sensitive and w/clock and w/enable and monolithic |
| Output Logic Form:   |
| Transistor-transistor logic  |
| Input Circuit Pattern:   |
| 16 input   |
| Current Rating Per Characteristic:   |
| 190.00 milliamperes reverse current, dc absolute                               |
| Product Name:  |
| Registered and-or gate array   |
| Time Rating Per Chacteristic:  |
| 20.00 nanoseconds propagation delay  |
| Memory Device Type:  |
| Pal  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| Yes - demil/mli  |
| Fiig:  |
| A458a0   |